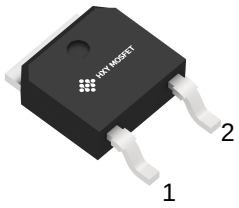
SICU0660P

Silicon Carbide Schottky Diode

Features

- 650-Volt Schottky Rectifier
- Zero Reverse Recovery Current
- Zero Forward Recovery Voltage
- High-Frequency Operation
- Temperature-Independent Switching Behavior
- Extremely Fast Switching
- Positive Temperature Coefficient on V_F



TO-252N-2L

Benefits

- Replace Bipolar with Unipolar Rectifiers
- Essentially No Switching Losses
- Higher Efficiency
- Reduction of Heat Sink Requirements
- Parallel Devices Without Thermal Runaway



Applications

- Switch Mode Power Supplies
- Power Factor Correction
- Motor Drives

Part Number	Package	Qty(PCS)
SICU0660P	TO-252N-2L	2500

Maximum Ratings (T_C = 25 ˚C unless otherwise specified)

Symbol	Parameter	Value	Unit	Test Conditions
V_{RRM}	Repetitive Peak Reverse Voltage	650	V	
V_{RSM}	Surge Peak Reverse Voltage	650	V	
I_F	Continuous Forward Current	21.4 9.9 6	A	T_C=25˚C T_C=135˚C T_C=156.5˚C
I_{FRM}	Repetitive Peak Forward Surge Current	30	A	T_C=25˚C, t_p = 10 ms, Half Sine Wave
I_{FSM}	Non-Repetitive Peak Forward Surge Current	66	A	T_C=25˚C, t_p = 10 ms, Half Sine Wave
P_{tot}	Power Dissipation	82 35	W	T_C=25˚C T_C=110˚C
T_J , T_{stg}	Operating Junction and Storage Temperature	-55 to +175	˚C	
$\int i^2dt$	i²dt value	22	A^2s	T_C=25˚C, t_p = 10 ms, Half Sine Wave

Electrical Characteristics

Symbol	Parameter	Min.	Typ.	Max.	Unit	Test Conditions
V_{DC}	DC Blocking Voltage	650			V	
V_F	Forward Voltage		1.36 1.64	1.7 2	V	I_F = 6 A T_J=25°C I_F = 6 A T_J=175°C
I_R	Reverse Current		0.12 0.91	50 100	μA	V_R = 650 V T_J=25°C V_R = 650 V T_J=175°C
Q_C	Total Capacitive Charge		22		nC	V_R = 400 V T_J = 25°C
C	Total Capacitance		440 42 41		pF	V_R = 0 V, T_J = 25°C, f = 1 MHz V_R = 200 V, T_J = 25°C, f = 1 MHz V_R = 400 V, T_J = 25°C, f = 1 MHz
E_C	Capacitance Stored Energy		5		μJ	V_R = 400 V

Thermal Characteristics

Symbol	Parameter	Typ.	Unit
$R_{\theta JC}$	Thermal Resistance from Junction to Case	1.84	°C/W

Typical Performance

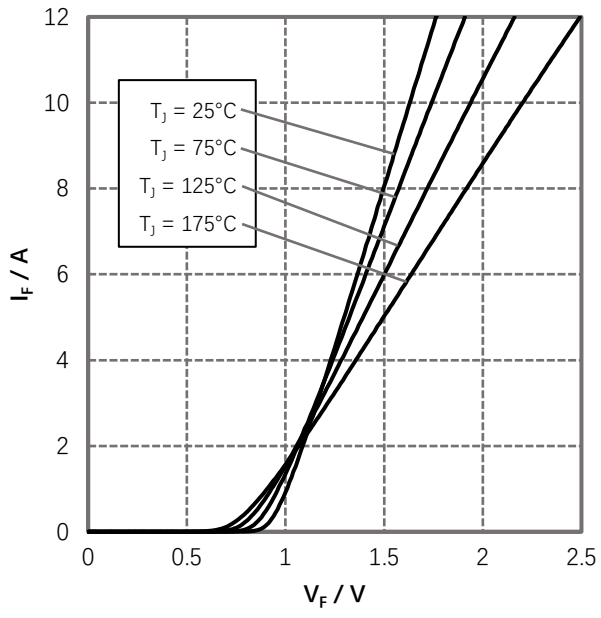


Figure 1. Forward Characteristics

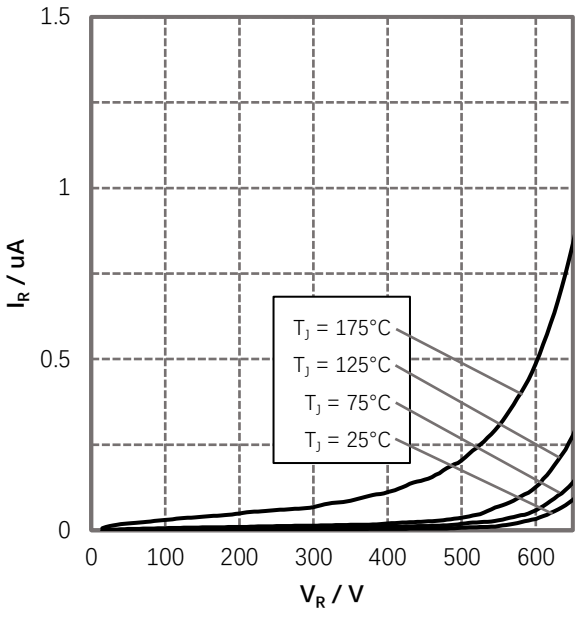


Figure 2. Reverse Characteristics

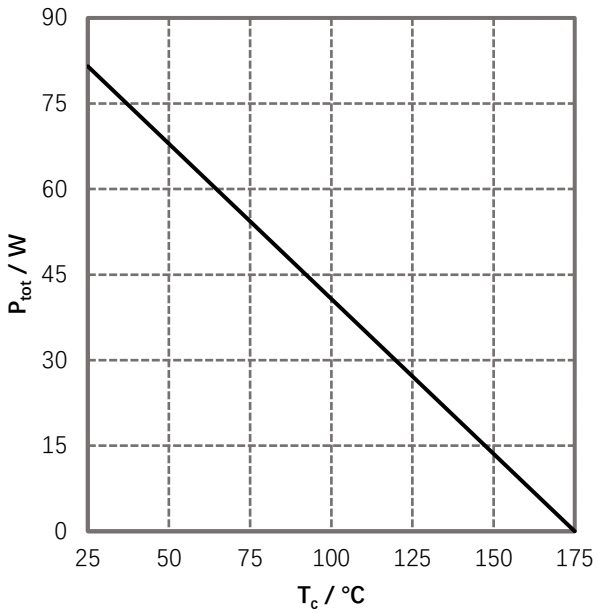


Figure 3. Power Derating

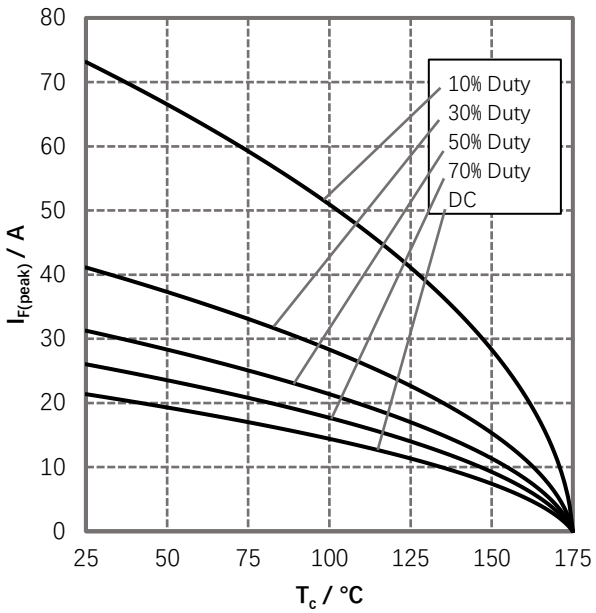


Figure 4. Current Derating

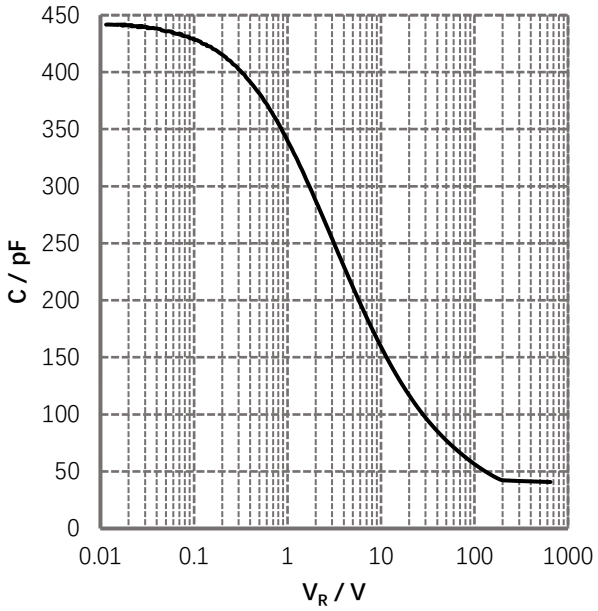


Figure 5. Capacitance vs. Reverse Voltage

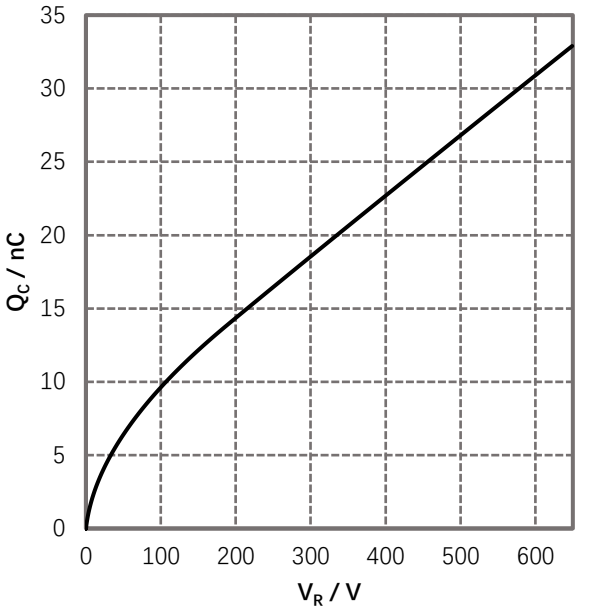


Figure 6. Total Capacitance Charge vs. Reverse Voltage

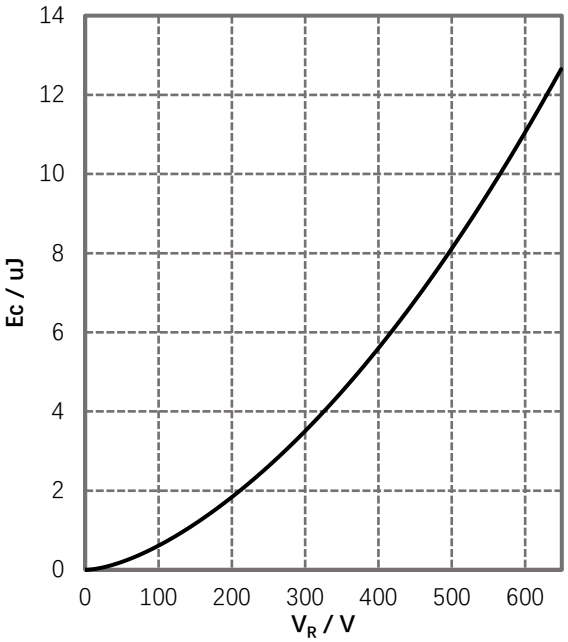


Figure 7. Capacitance Stored Energy

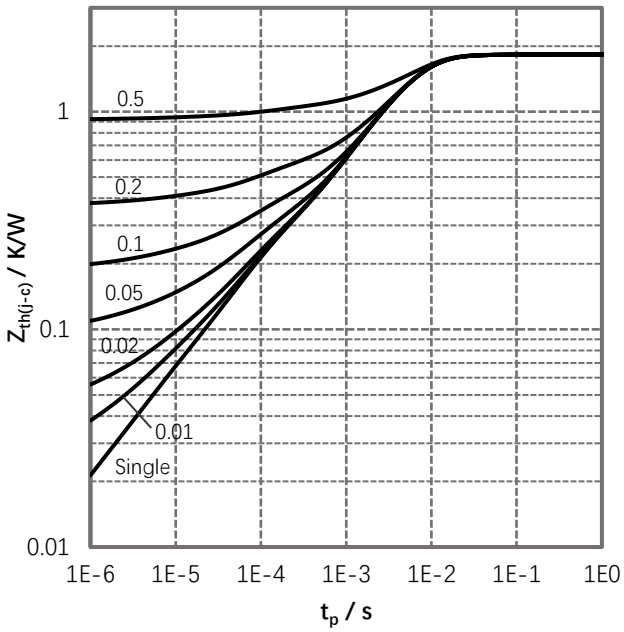
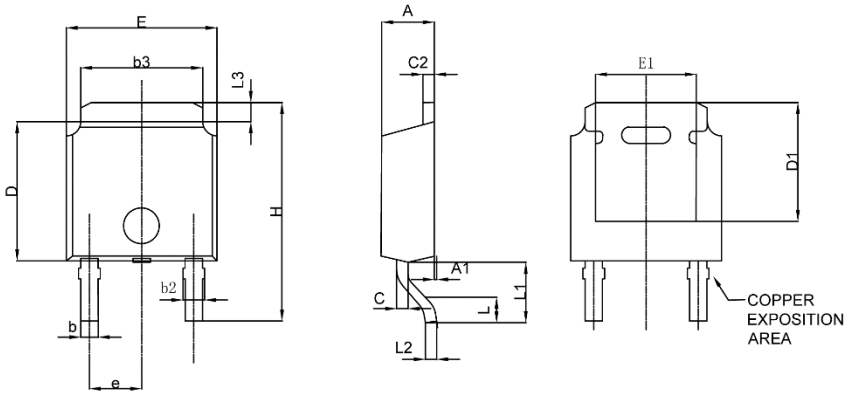


Figure 8. Transient Thermal Impedance

Package Information
TO-252N-2L



Symbol	DIMENSIONAL REQMTS		
	Min	Nom	Max
E	6.35	6.60	6.73
L	1.40	1.52	1.78
L1	2.743REF		
L2	0.508BSC		
L3	0.89	——	1.27
D	5.97	6.10	6.22
H	9.40	10.00	10.40
b	0.64	0.76	0.89
b2	0.76	0.84	1.14
b3	4.95	5.34	5.46
e	2.286BSC		
A	2.18	2.30	2.39
A1	0.00	——	0.13
c	0.46	0.50	0.61
c2	0.46	0.50	0.60
D1	5.21	——	——
E1	4.32	——	——

Note:
1.All Dimension Are In mm
2.Package Body Sizes Exclude Mold Flash,Protrusion Or Gate Burrs.
Mold Flash,Protrusion Or Gate Burrs Shall Not Exceed 0.10mm Per Side.
3.Package Body Sizes Determined At The Outermost Extremes
Of The Plastic Body Exclusive Of Mold Flash,
Gate Burrs And Interlead Flash,
But Including Any Mismatch Between
The Top And Bottom Of The Plastic Body.
4.The Package Top May Be Smaller Than The Package Bottom.
5.Dimension "b" Does Not Include Dambar Protrusion.
Allowable Dambar Protrusion Shall Be 0.10mm
Total In Excess Of "b" Dimension At Maximun Material Condition.
The Dambar Cannot Be Located On The Lower Radius Of The Foot.

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HRCLAMP3371ZCTFT PESDSC2FD5VU PJSD24CW_R1 RLSD32A121V 60N06 AZ4007-01H HESD36VD3B HPTVSUC3D5VB TPSMB100CA-VR ESD5LM5.0C-HXY HESDSLC3V3D3B HSEN3611D3 HSG3D15B3.3MA LM393DR-HXY PESDNC2XD5VBF TPSMB28A-VR BV05C-H HSD15C.TCT HSEN2411D3 HAZ4007-01H HCEZ36V,L3F PESDLC2FD3V3BH AZ4836-01L ESD5L5.0C-HXY HSTS521050B331 PJEC5V0M1FN2 AQ15C-01FTG HACPDQC5V0-HF PESDNC2XD5VBL HLY323BC1524L